

BC817-25W-QF Datasheet



https://www.DiGi-Electronics.com

DiGi Electronics Part Number BC817-25W-QF-DG

Manufacturer Nexperia USA Inc.

Manufacturer Product Number BC817-25W-QF

Description TRANS NPN 45V 0.5A SOT323

Detailed Description Bipolar (BJT) Transistor NPN 45 V 500 mA 100MHz 2

00 mW Surface Mount SOT-323



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

DiGi is a global authorized distributor of electronic components.



Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
BC817-25W-QF	Nexperia USA Inc.
Series:	Product Status:
BC817W-Q	Active
Transistor Type:	Current - Collector (Ic) (Max):
NPN	500 mA
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ lb, lc:
45 V	700mV @ 50mA, 500mA
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ Ic, Vce:
100nA (ICBO)	160 @ 100mA, 1V
Power - Max:	Frequency - Transition:
200 mW	100MHz
Operating Temperature:	Grade:
150°C (TJ)	Automotive
Qualification:	Mounting Type:
AEC-Q101	Surface Mount
Package / Case:	Supplier Device Package:
SC-70, SOT-323	SOT-323
Base Product Number:	
BC817	

Environmental & Export classification

8541.21.0075

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	



45 V, 500 mA NPN general-purpose transistors

Rev. 1 — 8 June 2021

Product data sheet

1. General description

NPN general-purpose transistor in a very small SOT323 (SC70) Surface-Mounted Device (SMD) plastic package.

Table 1. Product overview

Type number	Package	PNP complement		
	Nexperia	JEDEC	JEITA	
BC817W-Q	SOT323	-	SC-70	BC807W-Q
BC817-16W-Q				BC807-16W-Q
BC817-25W-Q				BC807-25W-Q
BC817-40W-Q				BC807-40W-Q

2. Features and benefits

- High current
- Three current gain selections
- · Qualified according to AEC-Q101 and recommended for use in automotive applications

3. Applications

· General-purpose switching and amplification

4. Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V_{CEO}	collector-emitter voltage	open base; T _{amb} = 25 °C		-	-	45	V
Ic	collector current	T _{amb} = 25 °C		-	-	500	mA
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms; T _{amb} = 25 °C		-	-	1	Α
h _{FE}	DC current gain						
	BC817W-Q	V _{CE} = 1 V; I _C = 100 mA T _{amb} = 25 °C	[1]	100	-	600	
	BC817-16W-Q		[1]	100	-	250	
	BC817-25W-Q		[1]	160	-	400	
	BC817-40W-Q		[1]	250	-	600	

[1] pulsed; $t_p \le 300 \ \mu s$; $\delta \le 0.02$



5. Pinning information

Table 3. Pinning

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base	<u></u> 3	С
2	Е	emitter		
3	С	collector		B—
				Ė
				sym123
			1 📙 🗀 2	

6. Ordering information

Table 4. Ordering information

Type number	Package	Package			
	Name	Description	Version		
BC817W-Q	SC-70	Plastic surface-mounted package; 3 leads	SOT323		
BC817-16W-Q					
BC817-25W-Q					
BC817-40W-Q					

7. Marking

Table 5. Marking

Type number	Marking code[1]			
BC817W-Q	6D%			
BC817-16W-Q	6A%			
BC817-25W-Q	6B%			
BC817-40W-Q	6C%			

[1] % = placeholder for manufacturing site code

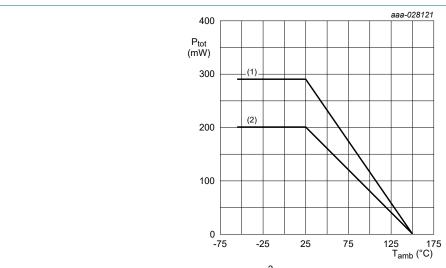
8. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CBO}	collector-base voltage	open emitter; T _{amb} = 25 °C	open emitter; T _{amb} = 25 °C			V
V _{CEO}	collector-emitter voltage	open base; T _{amb} = 25 °C		-	45	V
V _{EBO}	emitter-base voltage	open collector; T _{amb} = 25 °C		-	5	V
Ic	collector current	T _{amb} = 25 °C		-	500	mA
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms; T _{amb} = 25 °	single pulse; t _p ≤ 1 ms; T _{amb} = 25 °C			Α
I _{BM}	peak base current	single pulse; t _p ≤ 1 ms; T _{amb} = 25 °	single pulse; t _p ≤ 1 ms; T _{amb} = 25 °C			mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1] [2]	-	200	mW
			[3] [2]	-	290	mW
T _j	junction temperature					°C
T _{amb}	ambient temperature			-65	150	°C
T _{stg}	storage temperature			-65	150	°C

- [1] Device mounted on an FR4 Printed-Circuit-Board (PCB), single-sided copper, tin-plated and standard footprint.
- [2] Valid for all available selection groups.
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated; mounting pad for collector 1 cm².



- (1) FFR4 PCB, single-sided copper; 1 cm²
- (2) FR4 PCB, single-sided copper; standard footprint

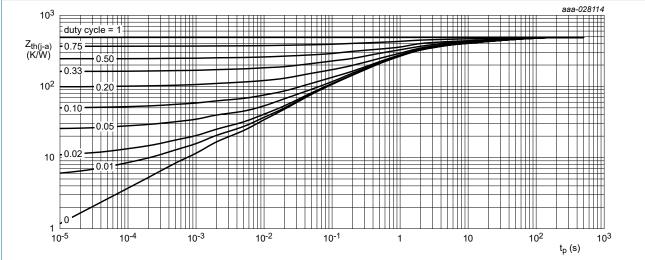
Fig. 1. Power derating curves

9. Thermal characteristics

Table 7. Thermal characteristics

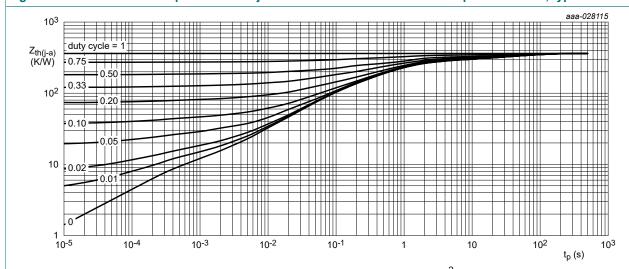
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	[1] [2]	-	-	625	K/W
			[3] [2]	-	-	431	K/W

- [1] Device mounted on an FR4 PCB; single-sided copper; tin-plated and standard footprint.
- [2] Valid for all available selection groups.
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated; monting pad for collector 1 cm².



FR4 PCB, single-sided, tin-plated and standard footprint

Fig. 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB, single-sided copper, tin-plated; mounting pad for collector 1 cm².

Fig. 3. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

45 V, 500 mA NPN general-purpose transistors

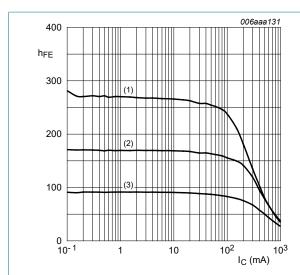
10. Characteristics

Table 8. Characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{(BR)CBO}	collector-base breakdown voltage	I _C = 100 μA; I _E = 0 A; T _{amb} = 25 °C		50	-	-	V
V _{(BR)CEO}	collector-emitter breakdown voltage	I _C = 10 mA; I _E = 0 A; T _{amb} = 25 °C		45	-	-	V
V _{(BR)EBO}	emitter-base breakdown voltage	I _E = 100 μA; I _C = 0 A; T _{amb} = 25 °C		5	-	-	V
I _{CBO}	collector-base	V _{CB} = 20 V; I _E = 0 A; T _{amb} = 25 °C		-	-	100	nA
	cut-off current	V _{CB} = 20 V; I _E = 0 A; T _j = 150 °C		-	-	5	μA
I _{EBO}	emitter-base cut-off current	V _{EB} = 5 V; I _C = 0 A; T _{amb} = 25 °C		-	-	100	nA
h _{FE}	DC current gain						
	BC817W-Q	V _{CE} = 1 V; I _C = 100 mA; T _{amb} = 25 °C	[1]	100	-	600	
	BC817-16W-Q		[1]	100	-	250	
	BC817-25W-Q		[1]	160	-	400	
	BC817-40W-Q		[1]	250	-	600	
h _{FE}	DC current gain	V _{CE} = 1 V; I _C = 500 mA; T _{amb} = 25 °C	[1]	40	-	-	
V _{CEsat}	collector-emitter saturation voltage	I _C = 500 mA; I _B = 50 mA; T _{amb} = 25 °C	[1]	-	-	700	mV
V_{BE}	base-emitter voltage	V _{CE} = 1 V; I _C = 500 mA; T _{amb} = 25 °C	[1] [2]	-	-	1.2	V
f _T	transition frequency	V _{CE} = 5 V; I _C = 10 mA; f = 100 MHz; T _{amb} = 25 °C		100	-	-	MHz
C _c	collector capacitance	$V_{CB} = 10 \text{ V}; I_E = i_e = 0 \text{ A}; f = 1 \text{ MHz};$ $T_{amb} = 25 \text{ °C}$		-	3	-	pF

pulsed; $t_p \le 300~\mu s;~\delta \le 0.02$ V_{BE} decreases by about 2 mV/K with increasing temperature.

45 V, 500 mA NPN general-purpose transistors



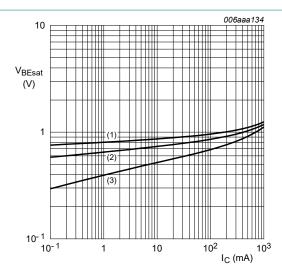
$$V_{CE} = 1 V$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 4. BC817-16W-Q: DC current gain as a function of collector current; typical values

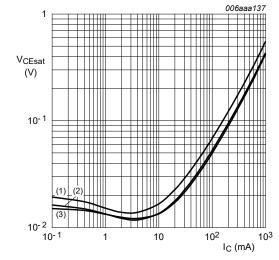


(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb}$$
 = 25 °C

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 5. BC817-16W-Q: Base-emitter saturation voltage as a function of collector current; typical values

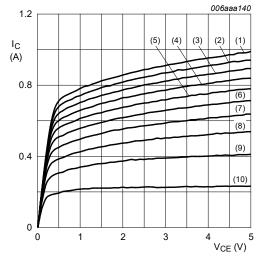


IC/IB = 10

(2)
$$T_{amb}$$
 = 25 °C

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 6. BC817-16W-Q: Collector-emitter saturation voltage as a function of collector current; typical values



T_{amb} = 25 °C

 $(1) I_B = 16.0 \text{ mA}$

(2) $I_B = 14.4 \text{ mA}$

(3) $I_B = 12.8 \text{ mA}$

(4) $I_B = 11.2 \text{ mA}$

(5) $I_B = 9.6 \text{ mA}$ (6) $I_B = 8.0 \text{ mA}$

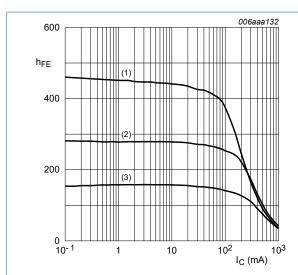
 $(7) I_B = 6.4 \text{ mA}$

(8) $I_B = 4.8 \text{ mA}$

(9) $I_B = 3.2 \text{ mA}$

 $(10) I_B = 1.6 \text{ mA}$

Fig. 7. BC817-16W-Q: Collector current as a function of collector-emitter voltage; typical values



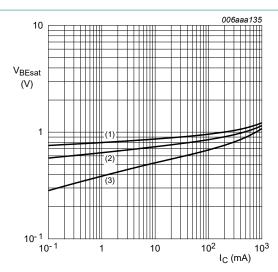
$$V_{CE} = 1 V$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 8. BC817-25W-Q: DC current gain as a function of collector current; typical values



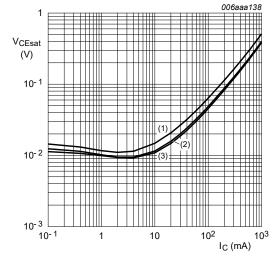
$$IC/IB = 10$$

(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 9. BC817-25W-Q: Base-emitter saturation voltage as a function of collector current; typical values

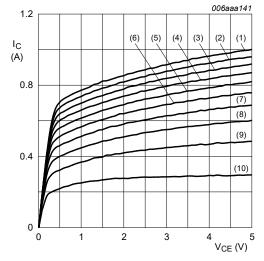


IC/IB = 10

(2)
$$T_{amb}$$
 = 25 °C

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 10. BC817-25W-Q: Collector-emitter saturation voltage as a function of collector current; typical values



$$(1) I_B = 13.0 \text{ mA}$$

(2)
$$I_B = 11.7 \text{ mA}$$

(3)
$$I_B = 10.4 \text{ mA}$$

(4)
$$I_B = 9.1 \text{ mA}$$

$$(5) I_B = 7.8 \text{ mA}$$

(6)
$$I_B = 6.5 \text{ mA}$$

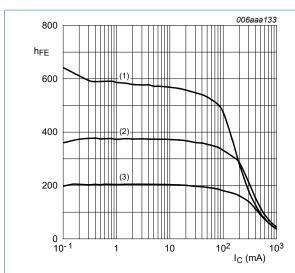
$$(7) I_B = 5.2 \text{ mA}$$

(8)
$$I_B = 3.9 \text{ mA}$$

(9)
$$I_B = 2.6 \text{ mA}$$

$$(10) I_B = 1.3 \text{ mA}$$

Fig. 11. BC817-25W-Q: Collector current as a function of collector-emitter voltage; typical values



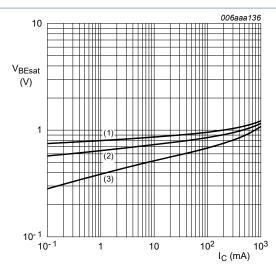
$$V_{CE} = 1 V$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

collector current; typical values

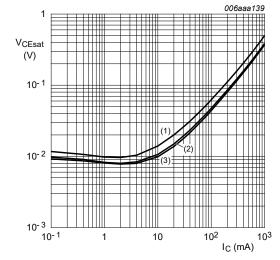


(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

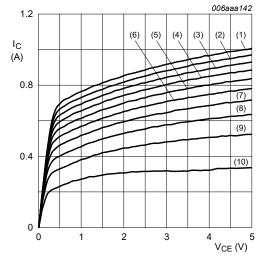
Fig. 12. BC817-40W-Q: DC current gain as a function of Fig. 13. BC817-40W-Q: Base-emitter saturation voltage as a function of collector current; typical values



IC/IB = 10

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 14. BC817-40W-Q: Collector-emitter saturation voltage as a function of collector current; typical values



(1)
$$I_B = 12.0 \text{ mA}$$

(2)
$$I_B = 10.8 \text{ mA}$$

(3)
$$I_B = 9.6 \text{ mA}$$

$$(4) I_B = 8.4 \text{ mA}$$

(5)
$$I_B = 7.2 \text{ mA}$$

(6)
$$I_B = 6.0 \text{ mA}$$

$$(7) I_B = 4.8 \text{ mA}$$

(8)
$$I_B = 3.6 \text{ mA}$$

(9)
$$I_B = 2.4 \text{ mA}$$

$$(10) I_B = 1.2 mA$$

Fig. 15. BC817-40W-Q: Collector current as a function of collector-emitter voltage; typical values

45 V, 500 mA NPN general-purpose transistors

11. Test information

11.1. Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

12. Package outline

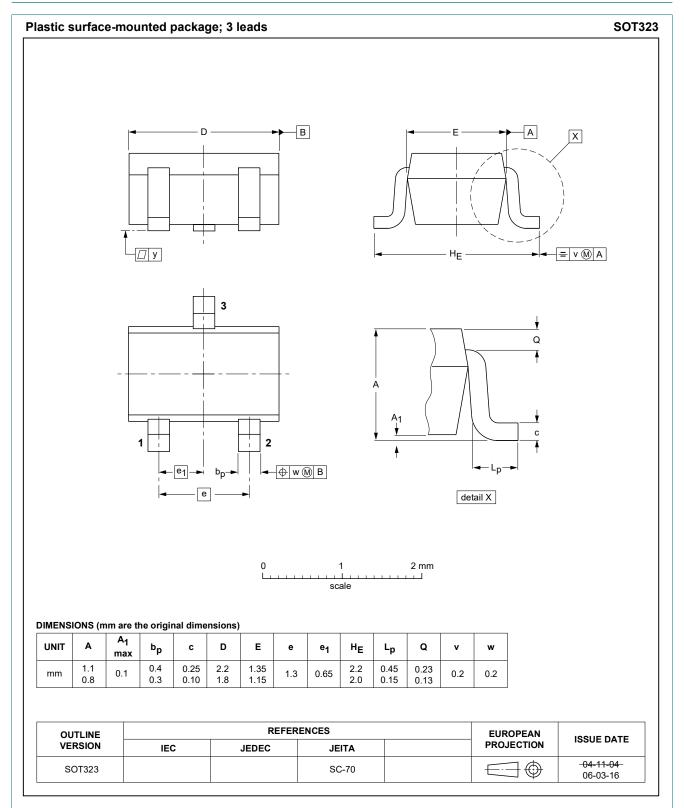
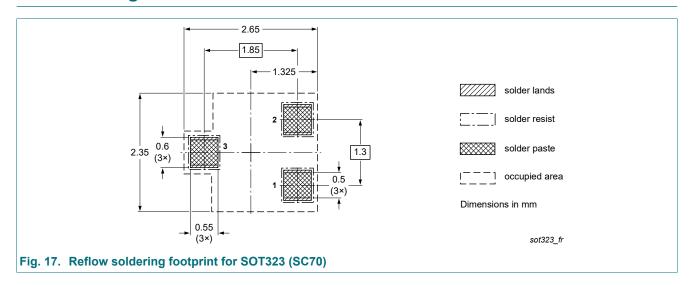
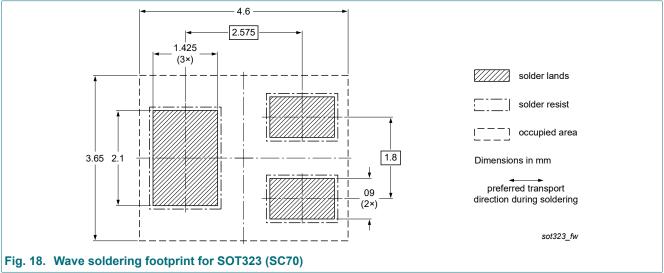


Fig. 16. Package outline SOT323 (SC70)

13. Soldering





45 V, 500 mA NPN general-purpose transistors

14. Revision history

Table 9. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
BC817W-Q_SER v.1	20210608	Product data sheet	-	-

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at https://www.nexperia.com.

Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. Nexperia does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local Nexperia sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

Product specification — The information and data provided in a Product data sheet shall define the specification of the product as agreed between Nexperia and its customer, unless Nexperia and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the Nexperia product is deemed to offer functions and qualities beyond those described in the Product data sheet.

Disclaimers

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, Nexperia does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. Nexperia takes no responsibility for the content in this document if provided by an information source outside of Nexperia.

In no event shall Nexperia be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, Nexperia's aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the Terms and conditions of commercial sale of Nexperia.

Right to make changes — Nexperia reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use in automotive applications — This Nexperia product has been qualified for use in automotive applications. Unless otherwise agreed in writing, the product is not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or

45 V, 500 mA NPN general-purpose transistors

equipment, nor in applications where failure or malfunction of an Nexperia product can reasonably be expected to result in personal injury, death or severe property or environmental damage. Nexperia and its suppliers accept no liability for inclusion and/or use of Nexperia products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

Quick reference data — The Quick reference data is an extract of the product data given in the Limiting values and Characteristics sections of this document, and as such is not complete, exhaustive or legally binding.

Applications — Applications that are described herein for any of these products are for illustrative purposes only. Nexperia makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using Nexperia products, and Nexperia accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the Nexperia product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

Nexperia does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using Nexperia products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). Nexperia does not accept any liability in this respect

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale — Nexperia products are sold subject to the general terms and conditions of commercial sale, as published at http://www.nexperia.com/profile/terms, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. Nexperia hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of Nexperia products by customer.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

Export control — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

Translations — A non-English (translated) version of a document is for reference only. The English version shall prevail in case of any discrepancy between the translated and English versions.

Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

45 V, 500 mA NPN general-purpose transistors

Contents

1.	General description	<i>'</i>
2.	Features and benefits	<i>'</i>
3.	Applications	٠ ١
4.	Quick reference data	1
	Pinning information	
	Ordering information	
	Marking	
	Limiting values	
	Thermal characteristics	
10.	. Characteristics	
11.	. Test information	9
11.	1. Quality information	9
12.	. Package outline	10
13.	. Soldering	1′
	. Revision history	
	Legal information	

For more information, please visit: http://www.nexperia.com For sales office addresses, please send an email to: salesaddresses@nexperia.com Date of release: 8 June 2021

[©] Nexperia B.V. 2021. All rights reserved



OUR CERTIFICATE

DiGi provide top-quality products and perfect service for customer worldwide through standardization, technological innovation and continuous improvement. DiGi through third-party certification, we striciy control the quality of products and services. Welcome your RFQ to Email: Info@DiGi-Electronics.com

















Tel: +00 852-30501935